NPN Silicon Epitaxial Planar Transistor



MCH3206

DC / DC Converter Applications

[MCH3206]

0.07

0.85

_0.15

(Top view)

1 : Base

2 : Emitter

3: Collector

SANYO : MCPH3

Package Dimensions

unit : mm 2194A

2.1

0.25

0.65

2.0

(Bottom view)

Applications

• Relay drivers, lamp drivers, motor drivers, strobes.

Features

- · Adoption of MBIT processes.
- High current capacitance.
- Low collector-to-emitter saturation voltage.
- High speed switching.
- Ultrasmall package facilitates miniaturization in end products (0.85mm).
- High allowable power dissipation.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	VCBO		15	V
Collector-to-Emitter Voltage	VCEO		15	V
Emitter-to-Base Voltage	VEBO		5	V
Collector Current	IC		3	А
Collector Current (Pulse)	ICP		5	А
Base Current	Ι _Β		600	mA
Collector Dissipation	PC	Mounted on a ceramic board(600mm ² X0.8mm)	0.8	W
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector Cutoff Current	ICBO	V _{CB} =12V, I _E =0			0.1	μΑ
Emitter Cutoff Current	IEBO	V _{EB} =4V, I _C =0			0.1	μΑ
DC Current Gain	hFE	V _{CE} =2V, I _C =500mA	200		560	
Gain-Bandwidth Product	fT	V _{CE} =2V, I _C =500mA		380		MHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		13		pF

Marking : CF

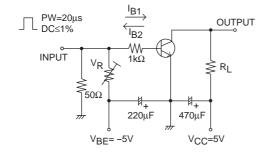
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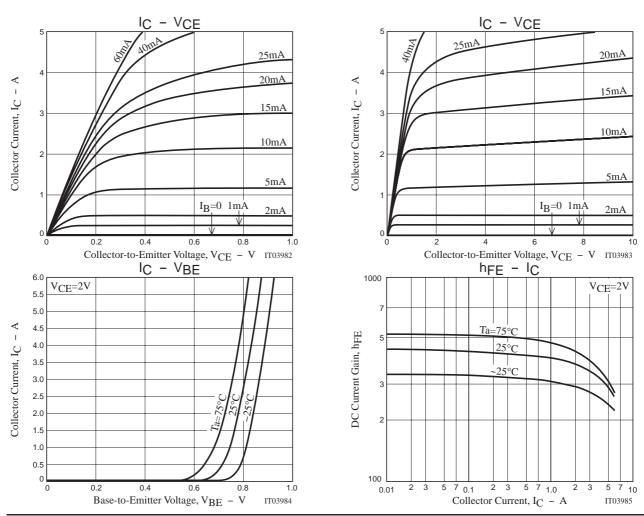
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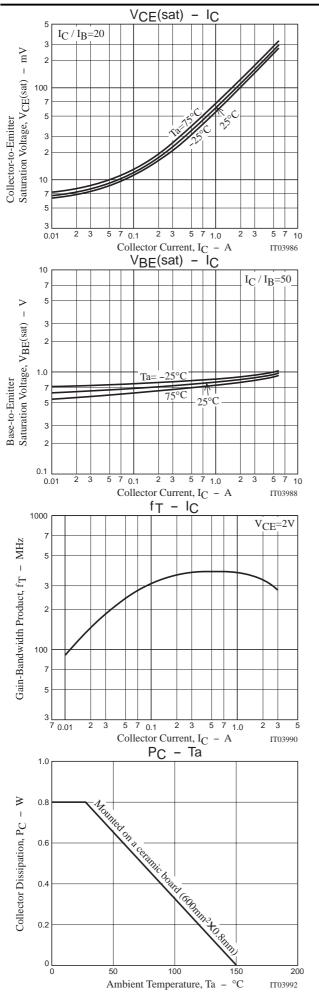
Parameter	Symbol	Conditions	Ratings			1.1
			min	typ	max	Unit
Collector-to-Emitter Saturation Voltage	V _{CE} (sat)1	IC=1.5A, IB=30mA		100	150	mV
	V _{CE} (sat)2	IC=3A, IB=60mA		180	270	mV
Base-to-Emitter Saturation Voltage	VBE(sat)	IC=1.5A, IB=30mA		0.85	1.2	V
Collector-to-Base Breakdown Voltage	V(BR)CBO	IC=10µA, IE=0	15			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	IC=1mA, RBE=∞	15			V
Emitter-to-Base Breakdown Voltage	V(BR)EBO	IE=10μA, IC=0	5			V
Turn-ON Time	ton	See specified Test Circuit.		30		ns
Storage Time	tstg	See specified Test Circuit.		210		ns
Fall Time	tf	See specified Test Circuit.		11		ns

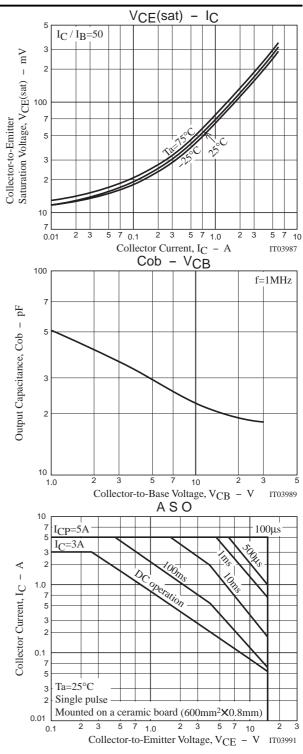
Switching Time Test Circuit



 $I_{C}=20I_{B1}=-20I_{B2}=1.5A$







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